## NSN 5961-00-109-0015

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-109-0015 **Inclosure Material:** Metal **Overall Length:** 1.247 inches **Overall Diameter:** 0.615 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -70.0 breakdown voltage, collector-to-base, emitter open and -50.0 breakdown voltage, collector-to-emitter, base open and -9.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 0.05 microamperes zero-gate-voltage source current preset and 10.00 microamperes zero-gate-voltage source current major **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Terminal surface gold **Precious Material:** Gold **Test Data Document:** 03640-6093588 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**